

2SC3324GRTE85LF

2SC3324GRTE85LF Information

www.Eelseper.com		2SC3324GRTE85LF Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single		
	Description	TRANS NPN 120V 0.1A S-MINI	RE-26-041	
	Package	TO-236-3, SC-59, SOT-23-3		
		For the pricing/inventory/lead time, please contact		
		us		
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2SC3324GRTE85LF Specifications

Manufacturer Part Number	2SC3324GRTE85LF	
Manufacturer	Toshiba Semiconductor and Storage	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	TO-236-3, SC-59, SOT-23-3	
Series	-	
Transistor Type	NPN	
Current - Collector (Ic) (Max)	100mA	
Voltage - Collector Emitter Breakdown (Max)	120V	
Vce Saturation (Max) @ Ib, Ic	300mV @ 1mA, 10mA	
Current - Collector Cutoff (Max)	100nA (ICBO)	
DC Current Gain (hFE) (Min) @ Ic, Vce	200 @ 2mA, 6V	
Power - Max	150mW	
Frequency - Transition	100MHz	
Operating Temperature	125°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	TO-236-3, SC-59, SOT-23-3	
Supplier Device Package	TO-236	
	Report errors?	

2SC3324GRTE85LF Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

2SC3324GRTE85LF Payment Methods



If you have any question about 2SC3324GRTE85LF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com